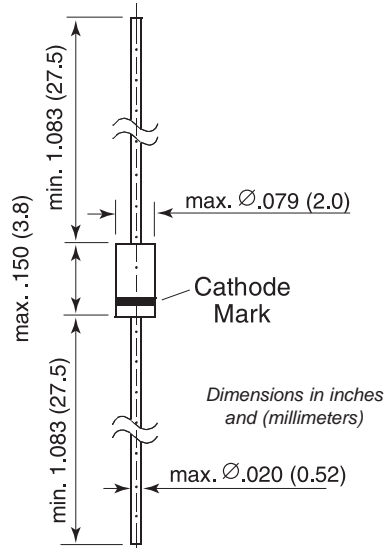


## Schottky Diodes

### DO-35 Glass



### Features

- For general purpose applications
- These diodes feature very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- These diodes are also available in the SOD-123 case with the type designations BAT42W to BAT43W and in designations LL42 to LL43.

### Mechanical Data

**Case:** DO-35 Glass Case

**Weight:** approx. 0.13g

### Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	30	V
Forward Continuous Current at $T_{amb} = 25^{\circ}C$	$I_F$	200 <sup>(1)</sup>	mA
Repetitive Peak Forward Current at $t_p < 1s, \delta < 0.5, T_{amb} = 25^{\circ}C$	$I_{FRM}$	500 <sup>(1)</sup>	mA
Surge Forward Current at $t_p < 10ms, T_{amb} = 25^{\circ}C$	$I_{FSM}$	4 <sup>(1)</sup>	A
Power Dissipation <sup>(1)</sup> at $T_{amb} = 65^{\circ}C$	$P_{tot}$	200 <sup>(1)</sup>	mW
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	300 <sup>(1)</sup>	$^{\circ}C/W$
Junction Temperature	$T_j$	125	$^{\circ}C$
Ambient Operating Temperature Range	$T_{amb}$	-65 to +125	$^{\circ}C$
Storage Temperature Range	$T_s$	-65 to +150	$^{\circ}C$

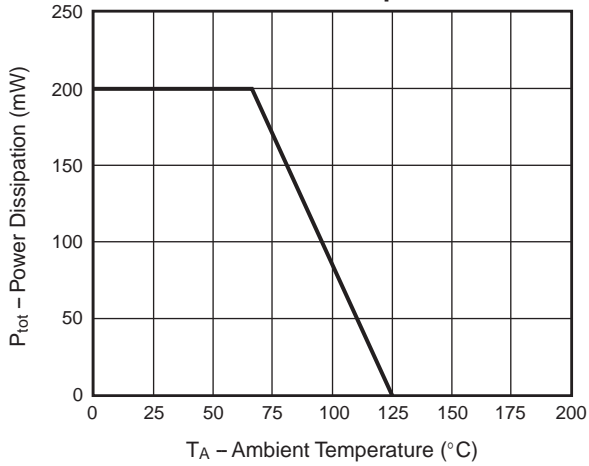
### Electrical Characteristics ( $T_J = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	$V_{(BR)R}$	$I_R = 100\mu A$ (pulsed)	30	—	—	V
Leakage Current Pulse Test $t_p < 300\mu s, \delta < 2\%$	$I_R$	$V_R = 25V$ $V_R = 25V, T_j = 100^{\circ}C$	—	—	0.5 100	$\mu A$
Forward Voltage Pulse Test $t_p < 300\mu s, \delta < 2\%$	$V_F$	BAT42, 43 BAT42 BAT43 BAT43 BAT43 $I_F = 200mA$ $I_F = 10mA$ $I_F = 50mA$ $I_F = 2mA$ $I_F = 15mA$	— — — 0.26 —	— — — — —	1 0.4 0.65 0.33 0.45	V
Capacitance	$C_{tot}$	$V_R = 1V, f = 1MHz$	—	7	—	pF
Reverse Recovery Time	$t_{rr}$	$I_F = 10mA, I_R = 10mA$ $I_{rr} = 1mA, R_L = 100\Omega$	—	—	5	ns
Detection Efficiency	$\eta_v$	$R_L = 15K\Omega, C_L = 300pF$ $f = 45MHz, V_{RF} = 2V$	80	—	—	%

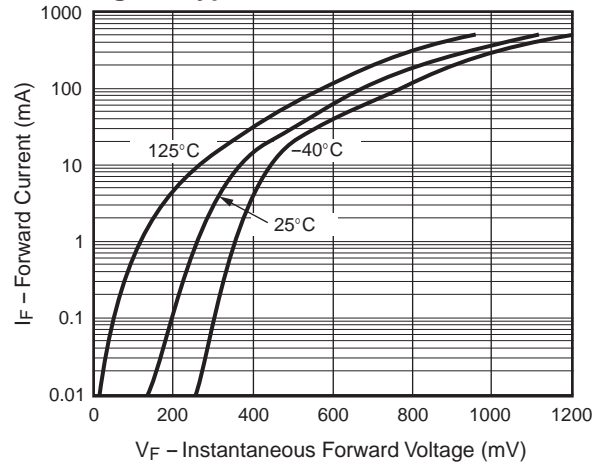
**Note:** (1) Valid provided that leads at a distance of 4mm from case are kept at ambient temperature

## Ratings and Characteristic Curves ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

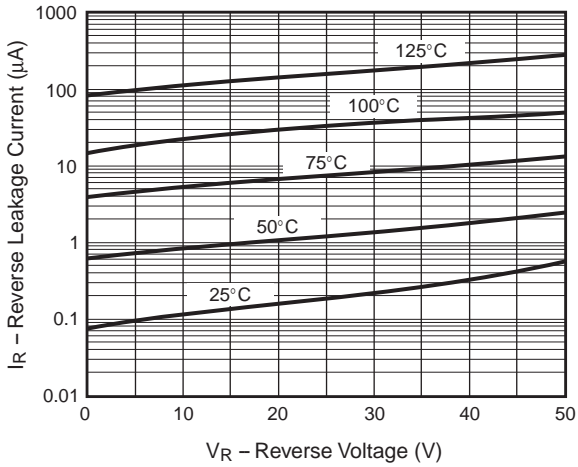
**Fig. 1 – Admissible Power Dissipation vs. Ambient Temperature**



**Fig. 2 – Typical Reverse Characteristics**



**Fig. 3 – Typical Reverse Characteristics**



**Fig. 4 – Typical Capacitance vs. Reverse Applied Voltage**

